

FIG. 1 is a perspective view of a device 10. The device 10 includes a substrate 22 having a top surface 28 and a bottom surface 26. A layer 24 is disposed on the top surface 28 of the substrate 22. The layer 24 includes a plurality of regions 25 and 27. The regions 25 are disposed in a row along the front edge of the substrate 22. The regions 27 are disposed in a row along the side edge of the substrate 22. A source of ions 20 is positioned above the device 10, and ions 30 are directed towards the top surface 28 of the substrate 22. A magnetic field 32 is applied to the device 10, as indicated by the arrow labeled SE_1 .

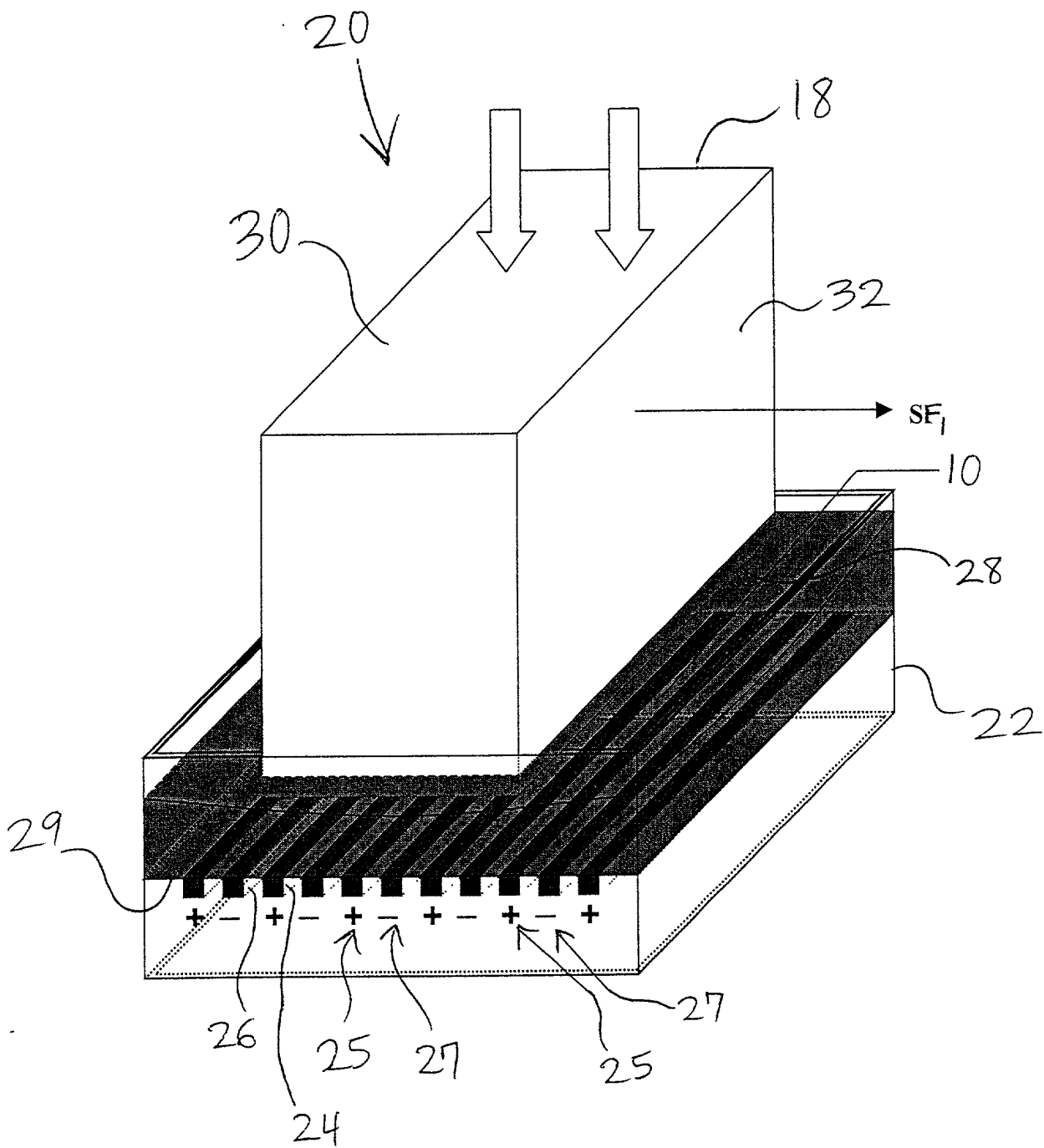


FIG. 1

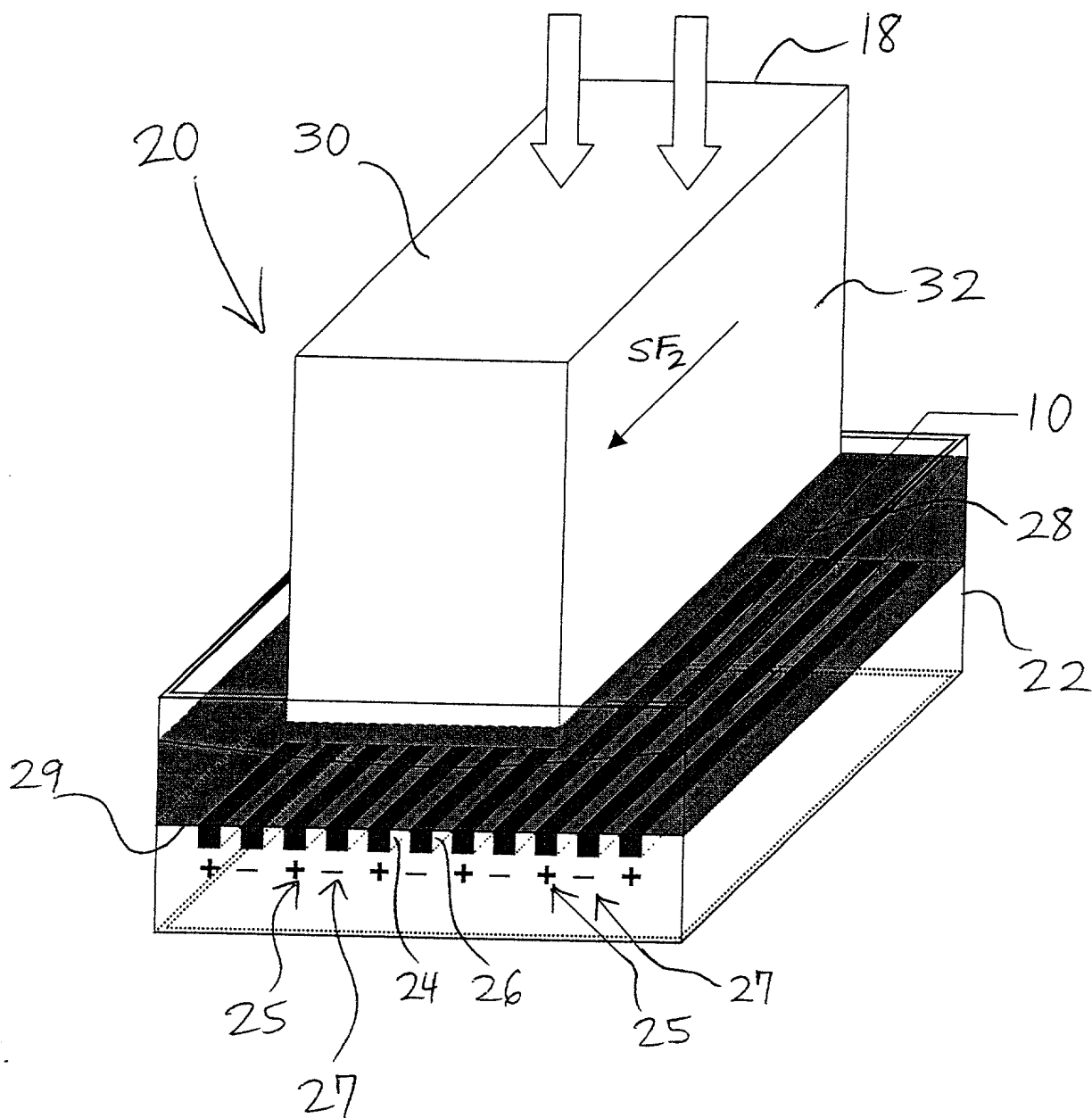


FIG. 2

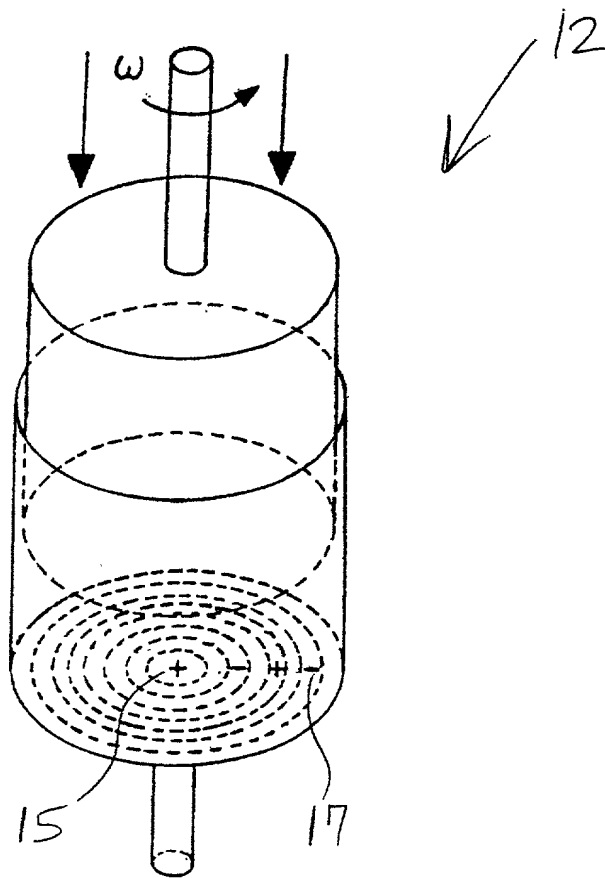


FIG. 3

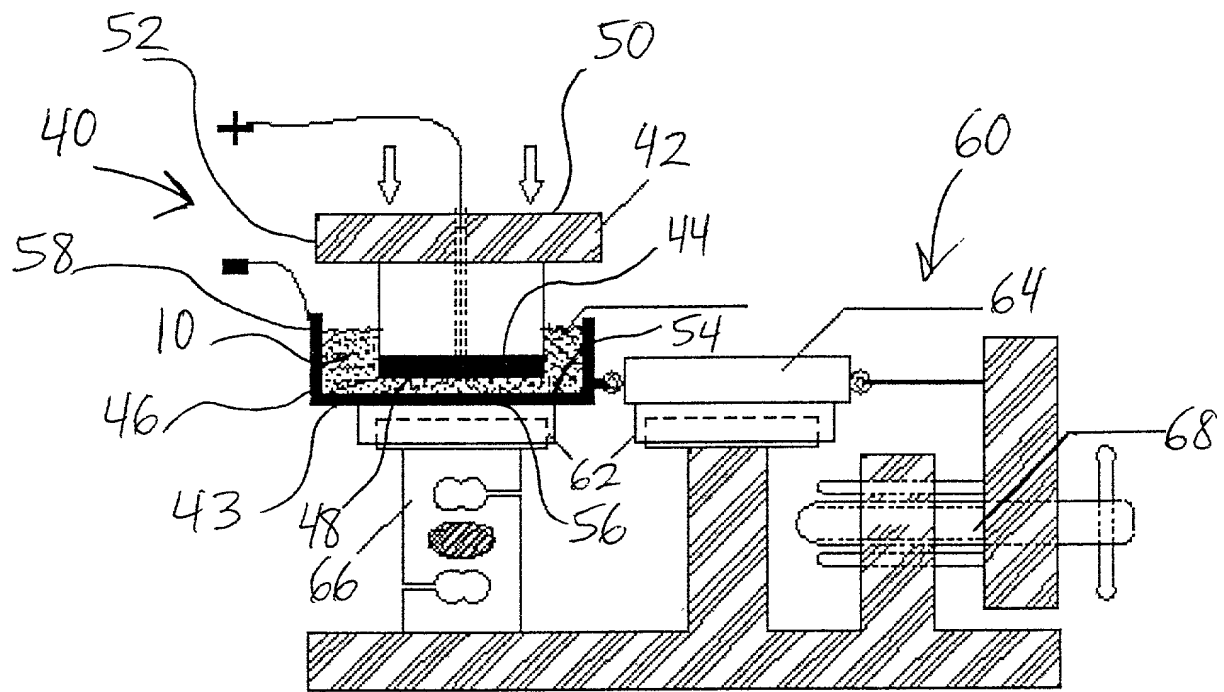


FIG. 4

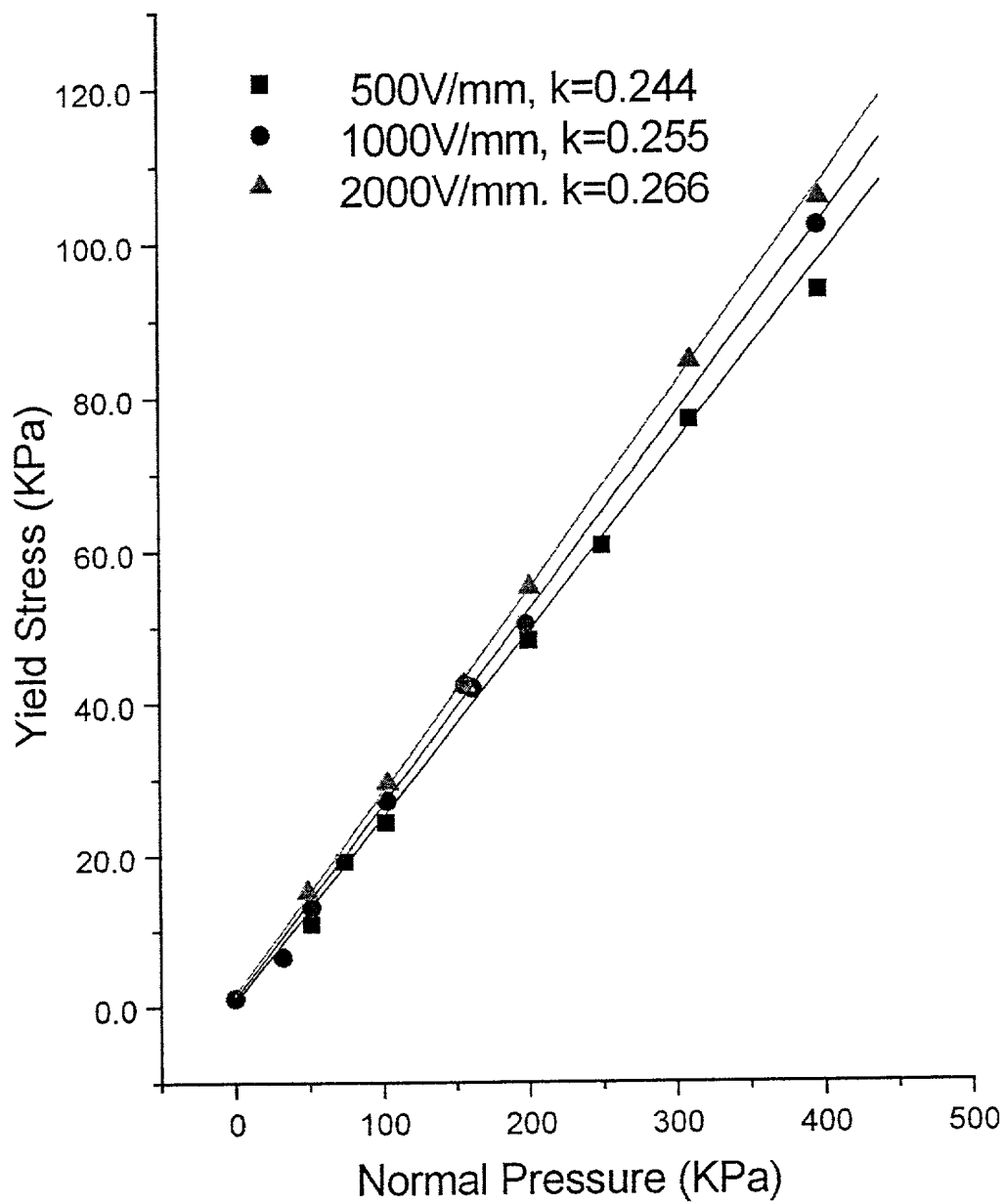


FIG. 5

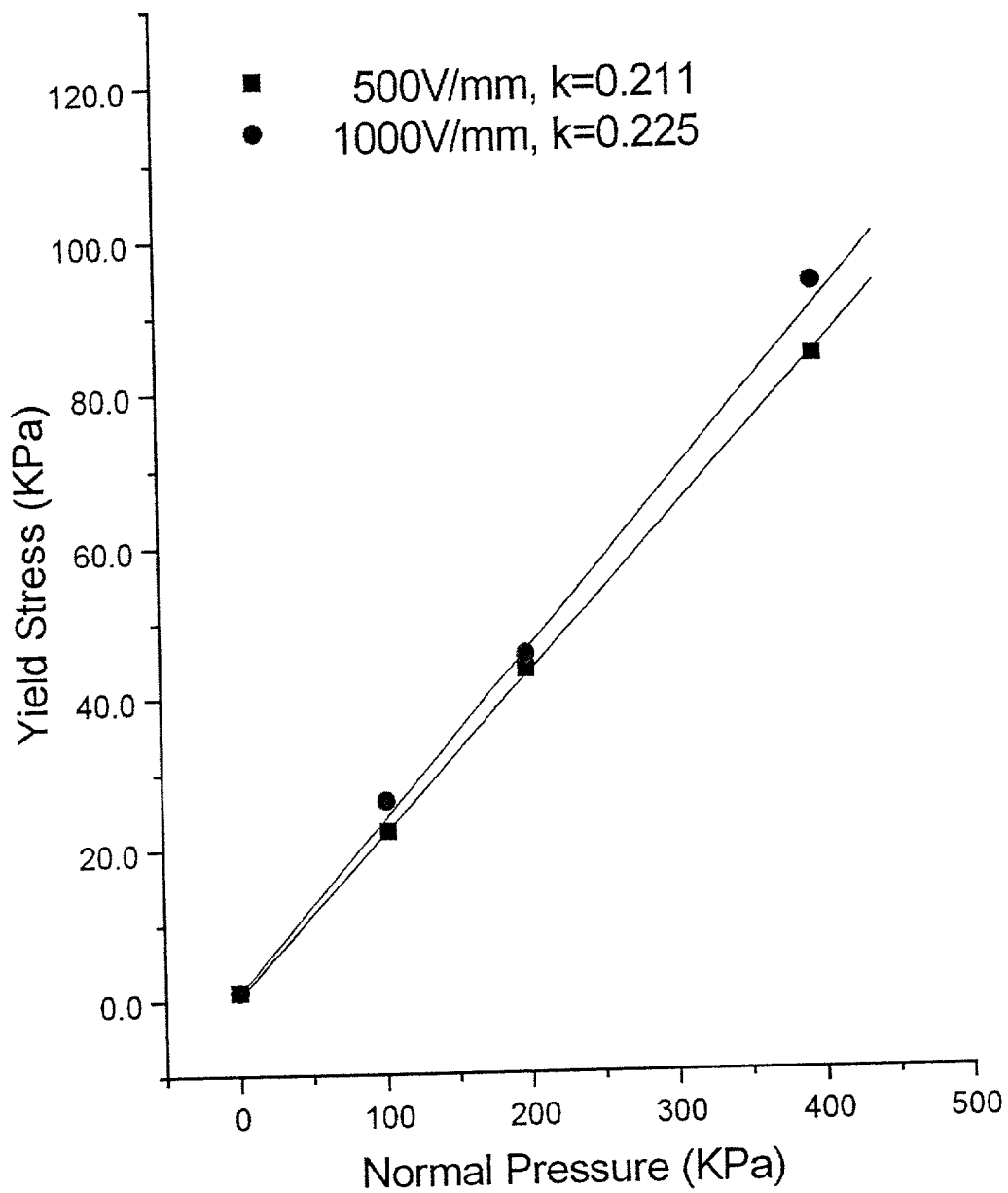


FIG. 6

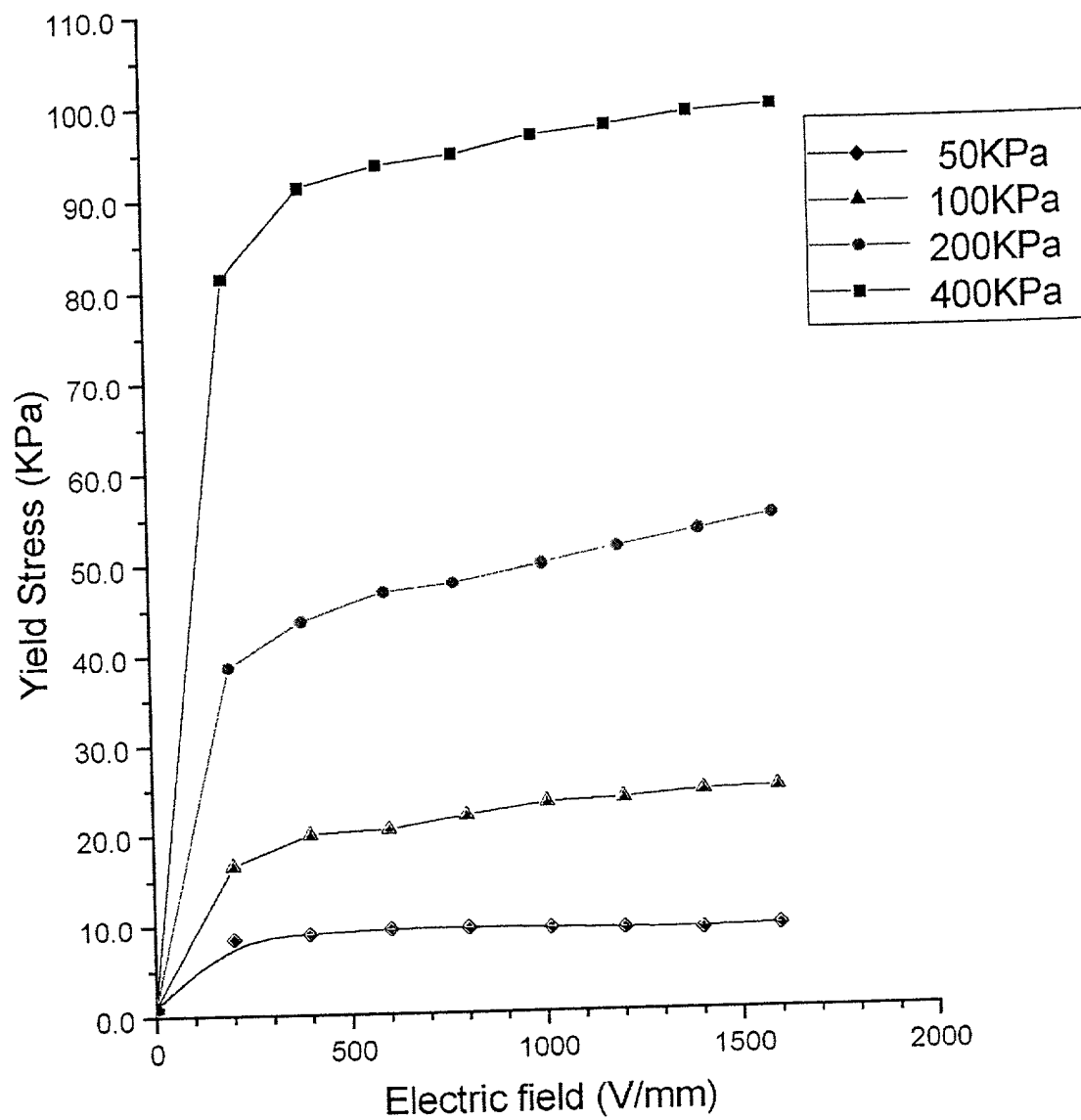


FIG. 7

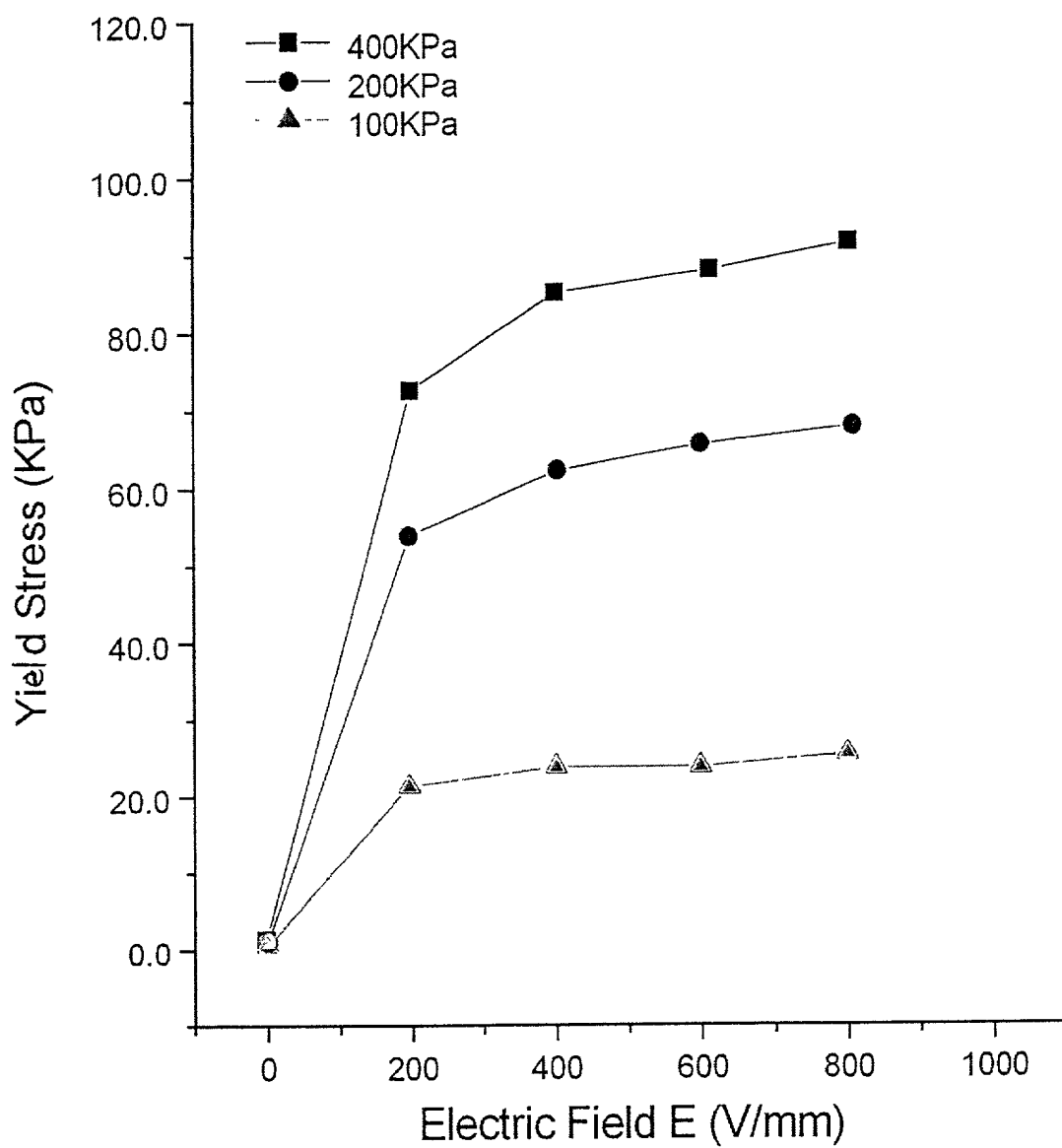


FIG. 8

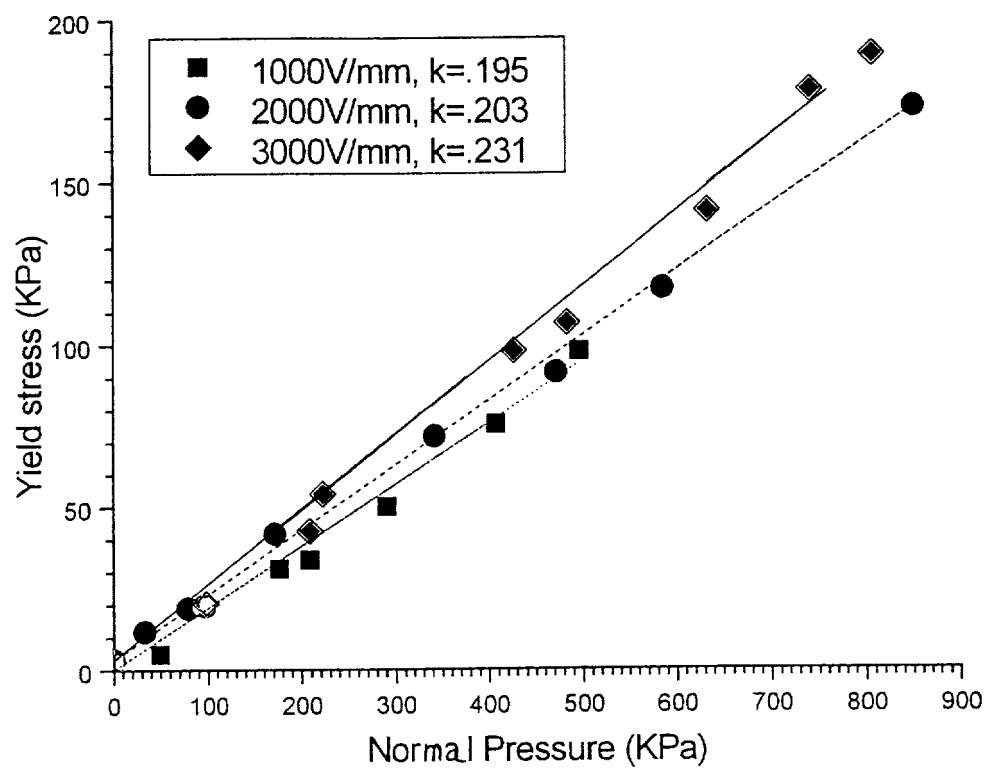


FIG. 9

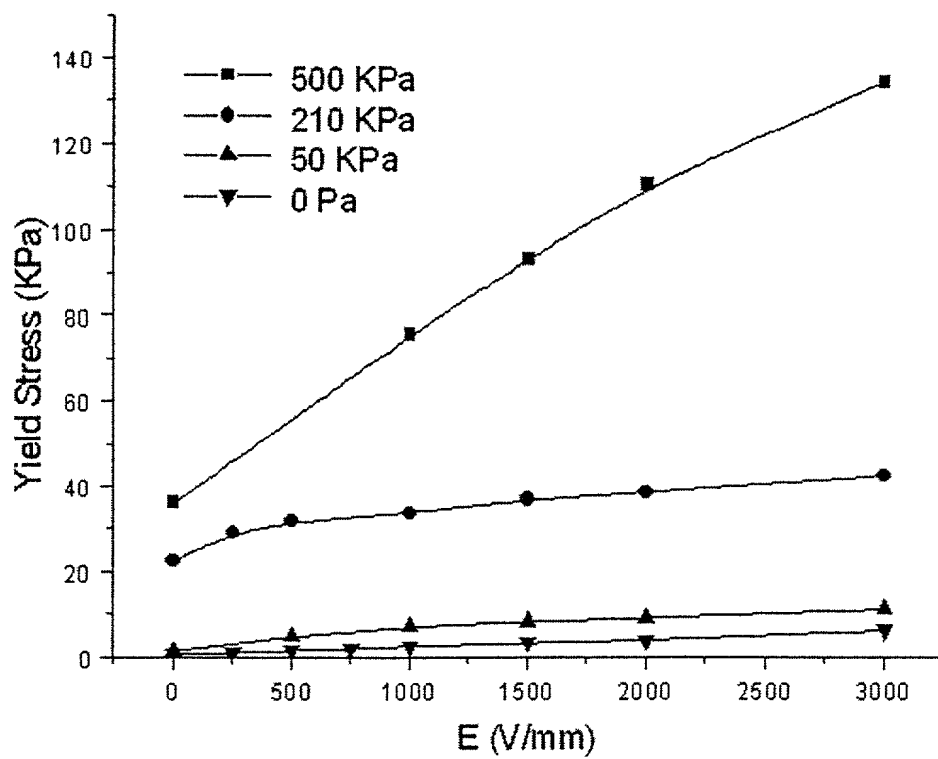


FIG.10